

WSJM80R200 Super-Junction Power MOSFET Rev.01 - 08 April 2024

Product data sheet

1. General description

WSJM80R200 is a high voltage N-channel MOSFET in TO220 package, which utilizes the advanced super-junction technology to provide superior FOM $R_{DS(on)}^*Q_g$ among silicon based MOSFETs. It is particularly suitable for applications require extreme high efficiency and power density.



2. Features and benefits

- Superior FOM R_{DS(on)} * Q_g
- Extremely low switching loss
- 100% avalanche tested

3. Applications

- EV charger
- High efficiency power supplies
- On board charger
- Inverters

4. Quick reference data

Table 1. Qu	lick reference data							
Symbol	Parameter	Conditions	Notes	Values		Unit		
Absolute	Absolute maximum rating							
V _{DS}	drain-source voltage				800		V	
V _{GS}	gate-source voltage				±30		V	
I _D	continuous drain current	T _{mb} = 25 °C		22		А		
P _{tot}	power dissipation	T _{mb} = 25 °C		272		W		
Tj	junction temperature			-55 to 150		°C		
Symbol	Parameter	Conditions	Notes	Min	Тур	Мах	Unit	
Static cha	aracteristics							
$R_{\text{DS(on)}}$	drain-source on-state resistance	V _{GS} = 10 V, I _D = 10.5 A		-	180	200	mΩ	
Dynamic	Dynamic characteristics							
Q _{G(tot)}	total gate charge	$I_{\rm D}$ = 10.5 A; $V_{\rm DS}$ = 640 V; $V_{\rm GS}$ = 10 V		-	52	-	nC	
E _{oss}	coss stored erergy	V_{GS} = 0 V; V_{DS} = 0 to 640 V		-	11	-	μJ	

5. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate	mb	D
2	D	drain		$\dot{\frown}$
3	S	source		
mb	D	mounting base; connected to drain		sym300 S

6. Ordering information

Table 3. Ordering information								
Type number	Package name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date		
WSJM80R200	TO220	WSJM80R200Q	Tube	50	SOT78	13-Jun-2008		

7. Marking

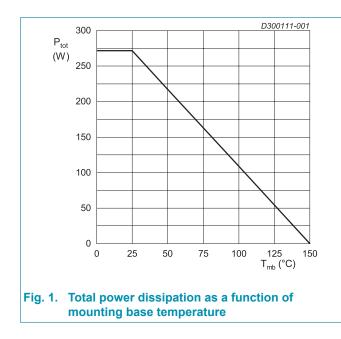
Table 4. Marking codes							
Type number	Marking codes						
WSJM80R200	WSJM 80R200						

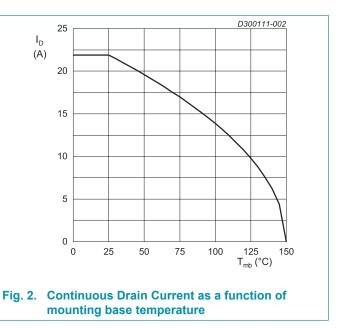
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Notes	Values	Unit
V _{DS}	drain-source voltage			800	V
V _{GS}	gate-source voltage			±30	V
I _D	continuous drain current	T _{mb} = 25 °C		22	А
		T _{mb} = 100 °C		14	А
I _{DM}	pulsed drain current	T _{mb} = 25 °C		88	А
P _{tot}	power dissipation	T _{mb} = 25 °C		272	W
E _{AS}	single pulse drain-to- source avalanche	I_{AS} = 13.5 A; R _{GS} = 25 Ω; V _{DD} = 50 V; T _j = 25 °C		911	mJ
E _{AR}	repetitive avalanche energy	I_{AS} = 13.5 A; R _{GS} = 25 Ω; V _{DD} = 50 V; T _j = 25 °C		0.64	mJ
I _{AS}	avalanche current, single pulse			13.5	A
dv/dt	MOSFET dv/dt ruggedness			50	V/ns
dv/dt	reverse diode dv/dt			15	V/ns
dI _F /dt	maximum diode commutation speed			500	A/µs
T _{stg}	storage temperature			-55 to 150	°C
T _j	junction temperature			-55 to 150	°C

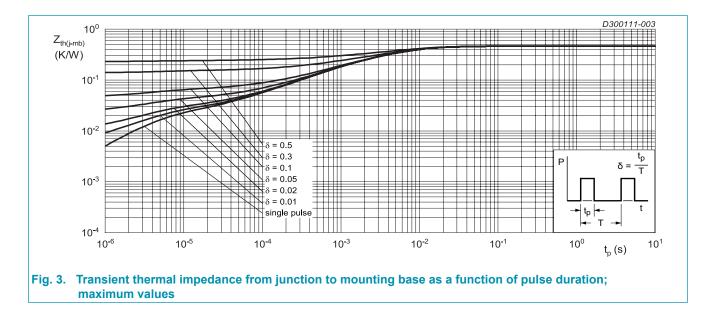




9. Thermal & Mechanical characteristics

Table 6. Thermal & Mechanical characteristics

Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base			-	0.35	0.46	K/W
R _{th(j-a)}	thermal resistance from junction to ambient	in free air		-	60	-	K/W



10. Characteristics

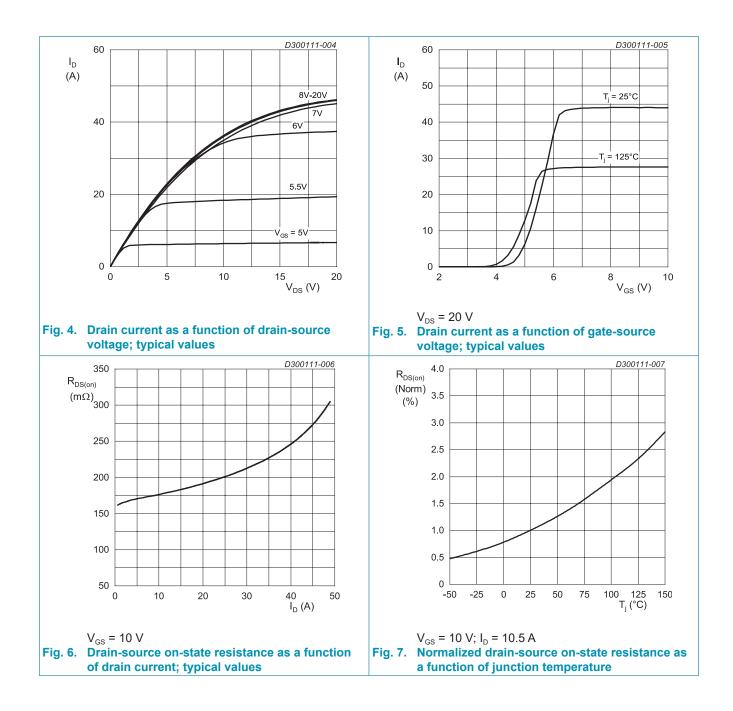
Table 7. Characteristics

T_j = 25 °C unless otherwise noted

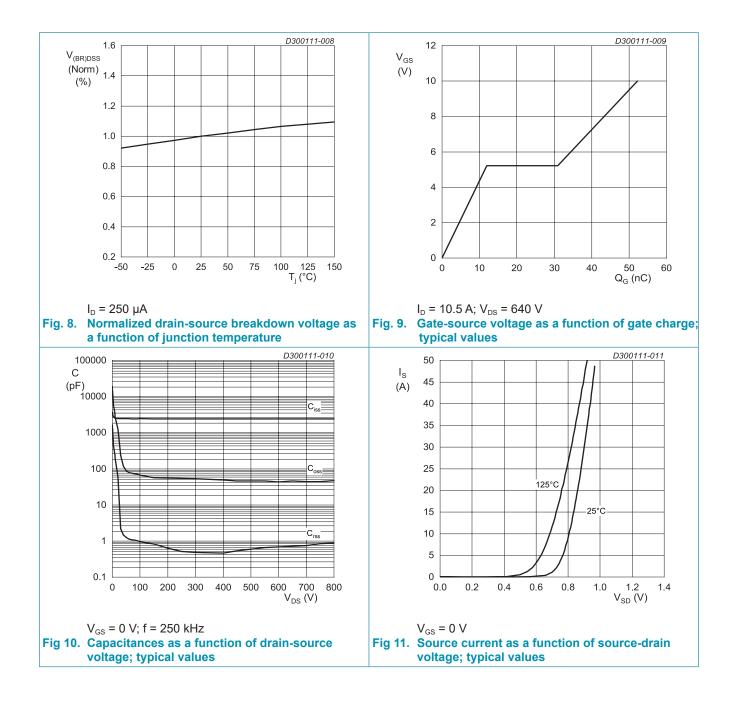
Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
Static cha	aracteristics						
$V_{(\text{BR})\text{DSS}}$	drain-source breakdown voltage	$I_{\rm D}$ = 250 µA; $V_{\rm GS}$ = 0 V		800	-	-	V
$V_{\text{GS(th)}}$	gate-source threshold voltage	I_D = 250 µA; V_{DS} = V_{GS}		2.5	-	4.5	V
I _{DSS}	drain leakage current	$V_{\rm DS}$ = 800 V; $V_{\rm GS}$ = 0 V		-	-	1	μA
		V_{DS} = 800 V; V_{GS} = 0 V; T_j = 125 °C		-	-	10	μA
I _{GSS}	gate leakage current	$V_{GS} = \pm 30 \text{ V}; V_{DS} = 0 \text{ V}$		-	-	±100	nA
$R_{\text{DS(on)}}$	drain-source on-state resistance	V_{GS} = 10 V; I _D = 10.5 A		-	180	200	mΩ
R _G	gate resistance	f = 1 MHz		-	1.8	-	Ω
Dynamic	characteristics						
Q _{G(tot)}	total gate charge	I_{D} = 10.5 A; V_{DS} = 640 V; V_{GS} = 10 V		-	52	-	nC
Q _{GS}	gate-source charge			-	12	-	nC
Q_{GD}	gate-drain charge			-	19	-	nC
C _{iss}	input capacitance	V_{DS} = 640 V; V_{GS} = 0 V; f = 250 kHz		-	2413	-	pF
C _{oss}	output capacitance			-	46	-	pF
C _{rss}	reverse transfer capacitance			-	0.7	-	pF
C _{o(er)}	effective output capacitance, energy related	V_{GS} = 0 V; V_{DS} = 0 to 640 V		-	52	-	pF
C _{o(tr)}	effective output capacitance, time related			-	221	-	pF
t _{d(on)}	turn-on delay time	$V_{DS} = 400 \text{ V}; V_{GS} = 10 \text{ V}; \text{ R}_{G} = 3 \Omega;$		-	16	-	ns
t _r	rise time	I _D = 10.5 A		-	11	-	ns
$t_{\rm d(off)}$	turn-off delay time			-	45	-	ns
t _f	fall time			-	8.5	-	ns
Source-d	rain diode						
V _{SD}	source-drain voltage	V _{GS} = 0 V; I _S = 10.5 A		-	0.8	1.1	V
l _s	body-diode continuous current	T _{mb} = 25 °C		-	-	22	A
t _{rr}	reverse recovery time	V_{R} = 400 V; I _F = 10.5 A; dI _F /dt = 100 A/		-	377	-	ns
Q _{rr}	reverse recovered charge	ha		-	6.4	-	μC
I _{rrm}	reverse recovery current			-	31	-	Α

WSJM80R200

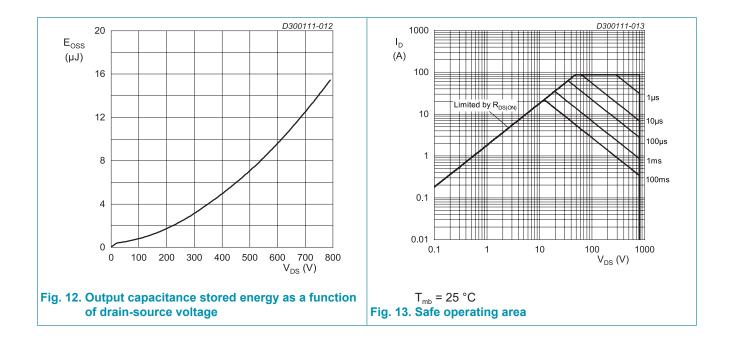
Super-Junction Power MOSFET



Super-Junction Power MOSFET



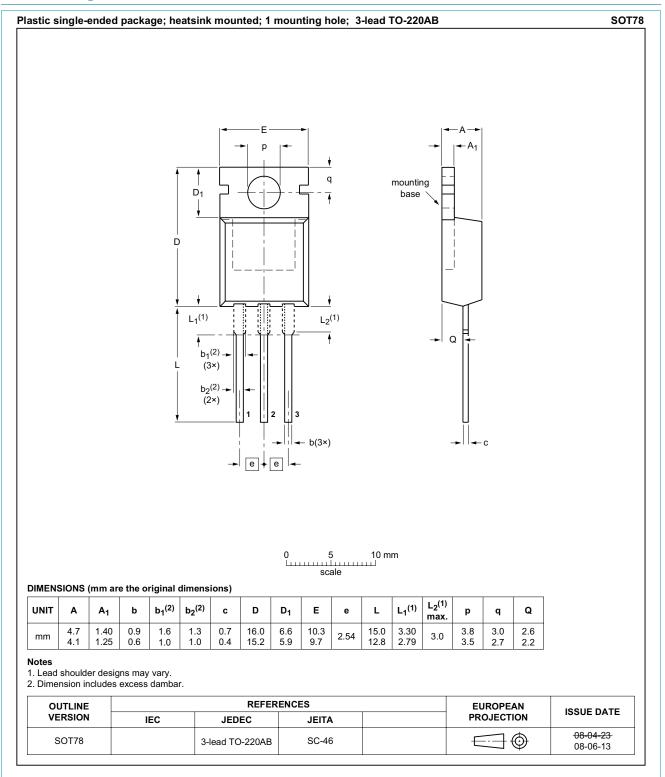
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WSJM80R200

Super-Junction Power MOSFET

11. Package outline



WSJM80R200 Product data sheet

WSJM80R200

Super-Junction Power MOSFET

12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
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